NSN 5962-01-203-4285

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View Online at https://aerobasegroup.com/nsn/5962-01-203-4285 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 635.0 milliwatts **Operating Tempurature Range:** -55.0/+100.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and ultraviolet erasable and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 26.5 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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